

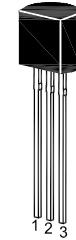
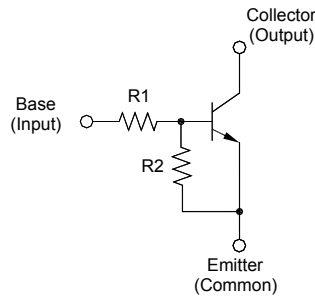
RC241...RC246

NPN Silicon Epitaxial Planar Transistors

for high current switching, interface circuit and driver circuit application.

Feature

- With Built-in Bias Resistor
- Simplify Circuit Design
- Reduce a Quantity of Parts and Manufacturing Process
- High Output Current



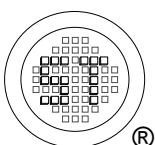
1. Emitter 2. Collector 3. Base
TO-92 Plastic Package

Resistor Values

Type	R1 (KΩ)	R2 (KΩ)
RC241	1	1
RC242	2.2	2.2
RC243	4.7	4.7
RC244	10	10
RC245	1	10
RC246	2.2	10

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Output Voltage	V_o	50	V
Input Voltage	V_i	10, -10	V
		12, -10	
		20, -10	
		30, -10	
		10, -5	
		12, -6	
Output Current	I_o	800	mA
Total Power Dissipation	P_{tot}	400	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150	$^\circ\text{C}$



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ISO/TS 16949 : 2009
Certificate No. 18073000



ISO14001 : 2004
Certificate No. 7116



ISO 9001 : 2008
Certificate No. 50713410



BS-OHSAS 18001 : 2007
Certificate No. 7116



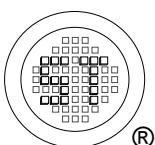
IECQ QC 080000
Certificate No. PRC-HSP4-1483-1

RC241...RC246

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_O = 5\text{ V}$, $I_O = 50\text{ mA}$	RC241	33	-	-	-
	RC242	39	-	-	-
	RC243	47	-	-	-
	RC244	56	-	-	-
	RC245	56	-	-	-
	RC246	56	-	-	-
Output Cutoff Current at $V_O = 30\text{ V}$	$I_{O(\text{OFF})}$	-	-	10	μA
Input Current at $V_I = 5\text{ V}$	RC241	-	-	7.2	mA
	RC242	-	-	3.8	
	RC243	-	-	1.8	
	RC244	-	-	0.88	
	RC245	-	-	7.2	
	RC246	-	-	3.6	
Output Voltage at $I_O = 50\text{ mA}$, $I_I = 2.5\text{ mA}$	$V_{O(\text{ON})}$	-	-	0.3	V
Input Voltage (ON) at $V_O = 0.3\text{ V}$, $I_O = 20\text{ mA}$	RC241	-	-	3	V
	RC242	-	-	3	
	RC243	-	-	3	
	RC244	-	-	3	
	RC245	-	-	3	
	RC246	-	-	2	
Input Voltage (OFF) at $V_O = 5\text{ V}$, $I_O = 0.1\text{ mA}$	RC241~244	0.5	-	-	V
	RC245~246	0.3	-	-	
Transition Frequency at $V_O = 10\text{ V}$, $I_O = 5\text{ mA}$, $f = 100\text{ MHz}$	f_T ¹⁾	-	200	-	MHz

¹⁾ Characteristic of transistor only.



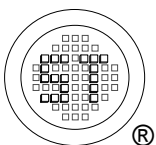
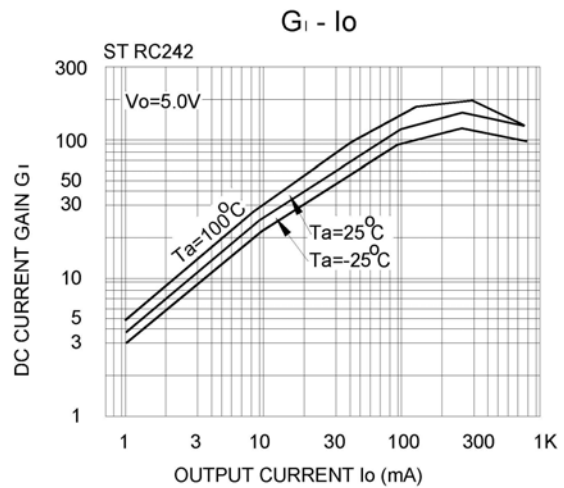
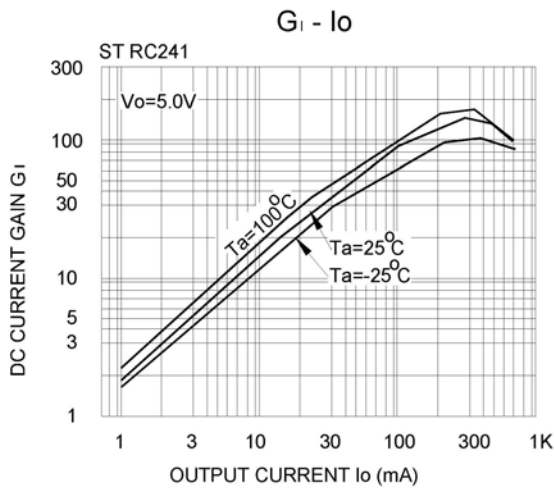
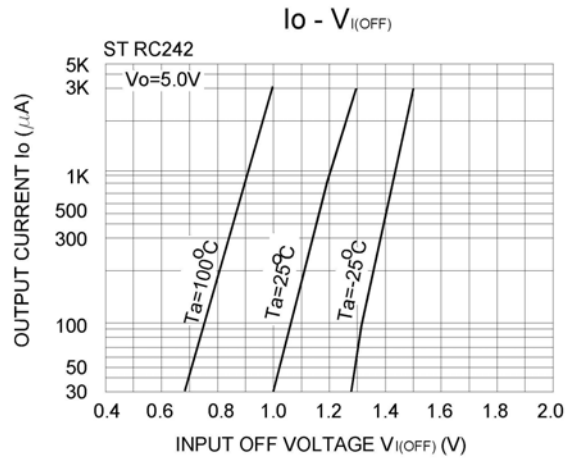
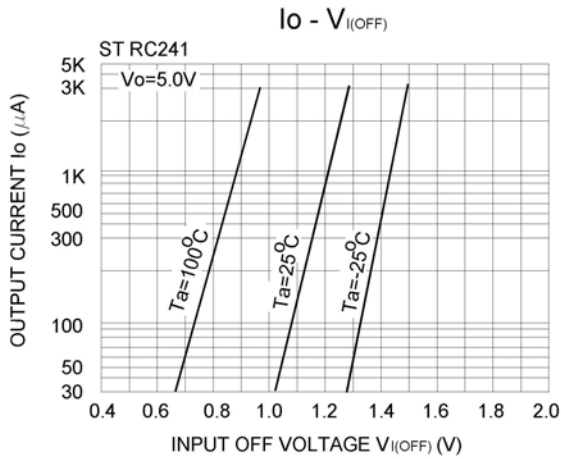
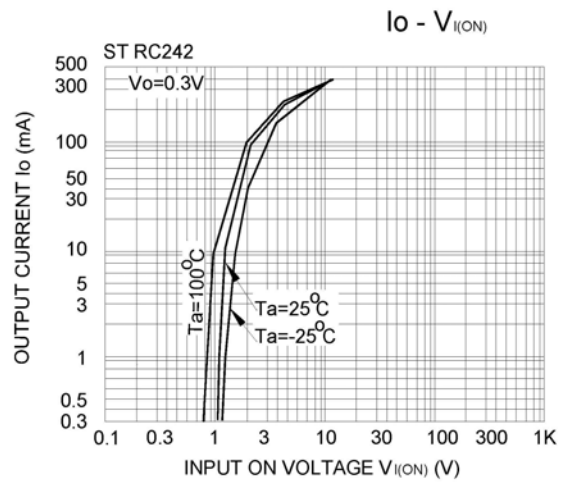
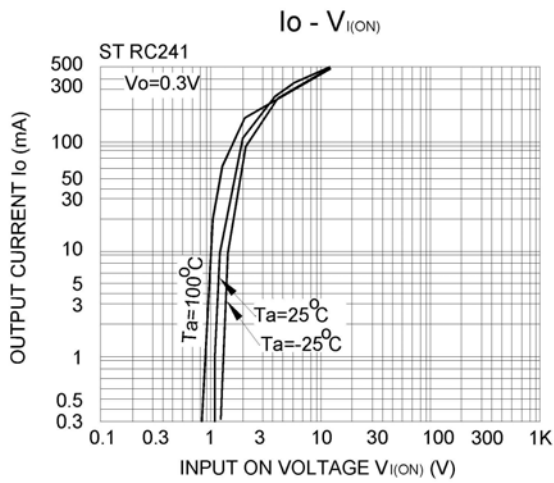
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 BS-OHSAS 18001 : 2007 Certificate No. 7116
 IECQ QC 080000 Certificate No. PRC-HSP4-1483-1

Dated: 23/08/2016 Rev: 05

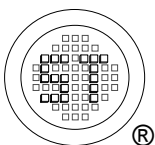
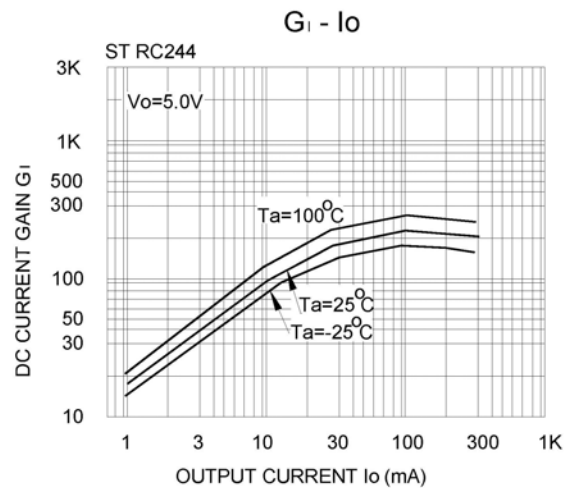
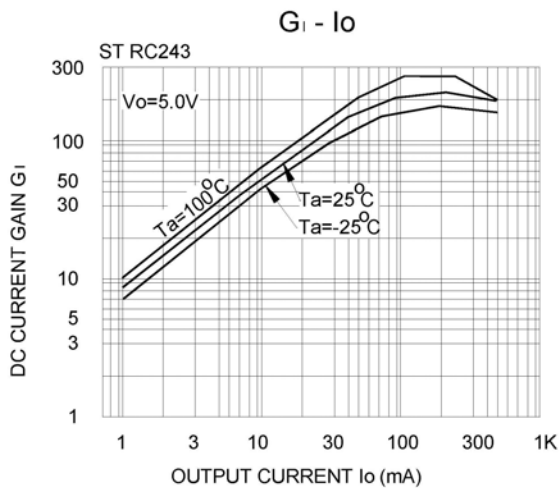
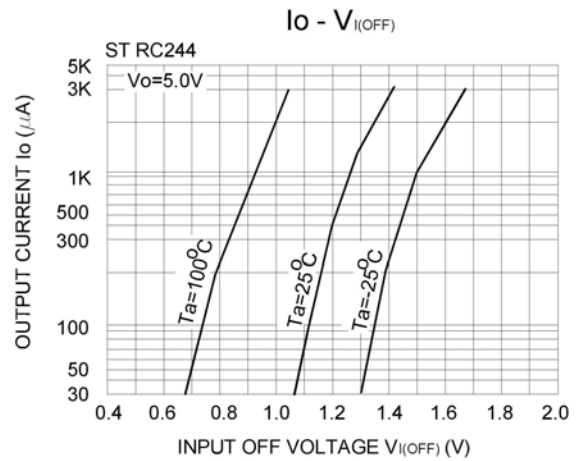
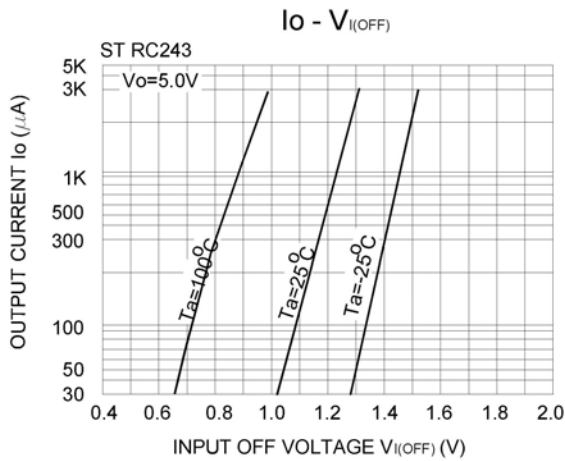
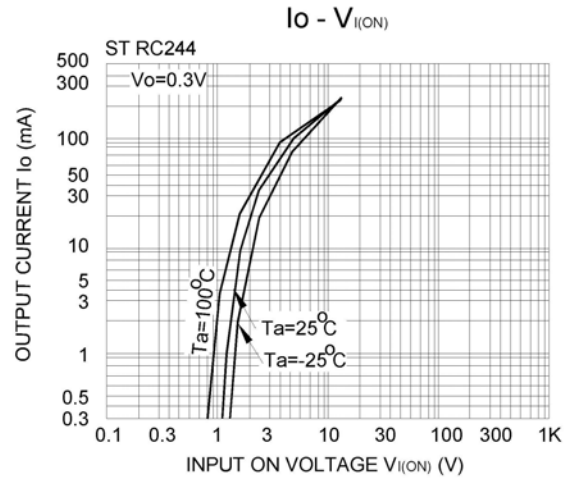
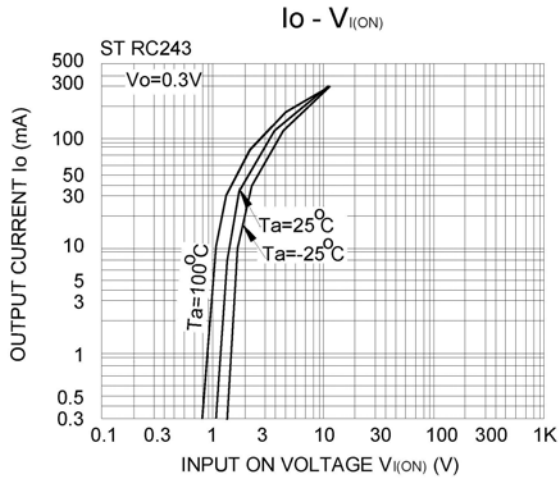
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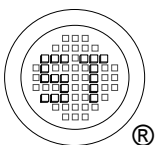
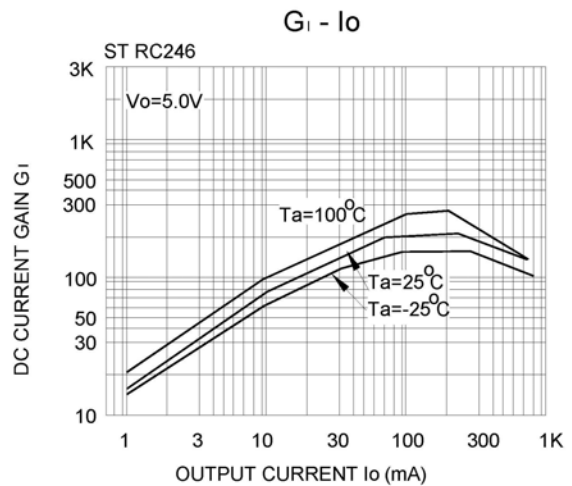
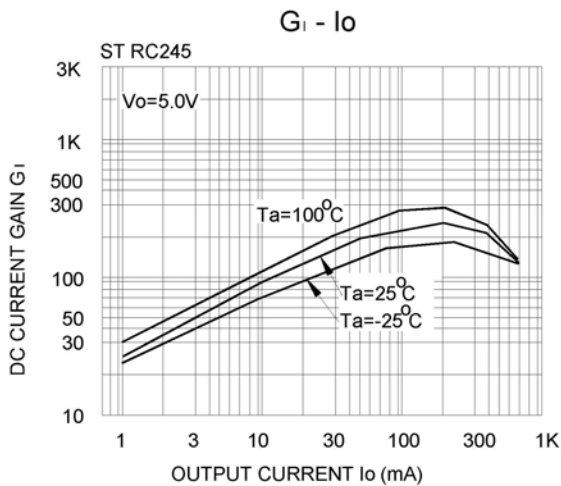
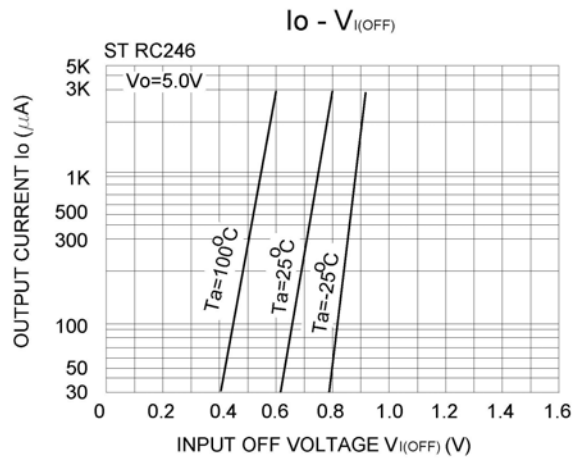
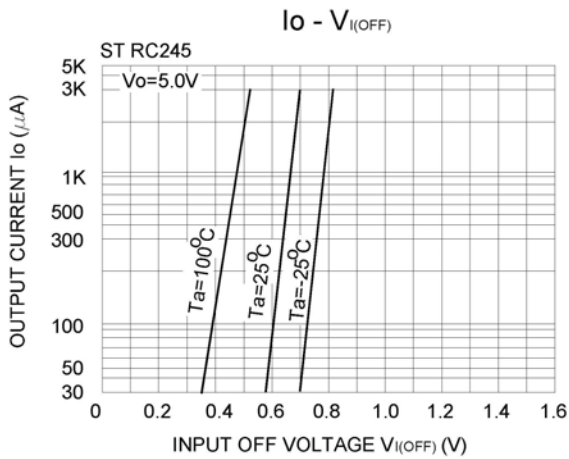
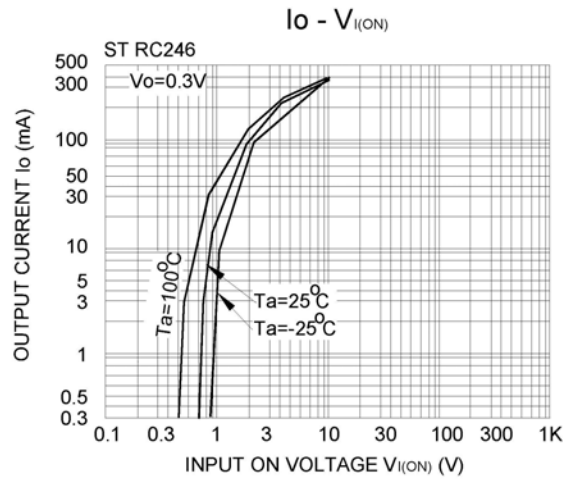
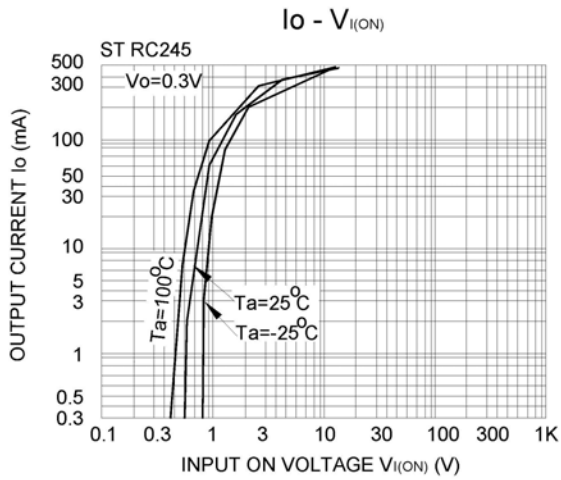
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